

# Photonic Crystal Slot Waveguide Spectrometer for Detection of Methane

Swapnajit Chakravarty <sup>1</sup>, Wei-Cheng Lai <sup>2</sup>, Xiaolong (Alan) Wang <sup>1</sup>,  
Che-Yun Lin <sup>2</sup>, Ray T. Chen <sup>1,2</sup>

<sup>1</sup> Omega Optics, 10306 Sausalito Drive, Austin, TX 78759

<sup>2</sup> Dept. of Electrical and Computer Engineering, University of Texas, Austin

Funded by Environmental Protection Agency (EPA)  
SBIR Grant #: EP-D-10-047

# Motivation

No other chip based optical method for infrared molecular absorption spectroscopy of gases



Cavity Ringdown Spectroscopy  
(66lbs, ~ 3cu.ft)



FTIR Spectroscopy  
(24lbs, ~ 1.5cu.ft.)

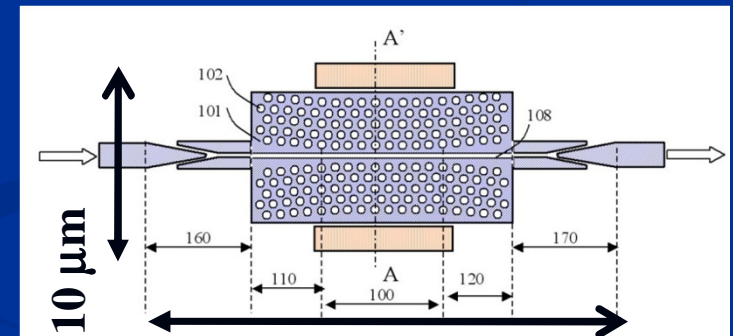


Tunable Diode Laser Absorption  
Spectroscopy



Photoacoustic  
Spectroscopy  
(33lbs, ~ 1cu.ft)

## Our Device

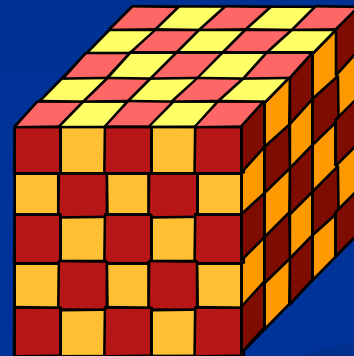
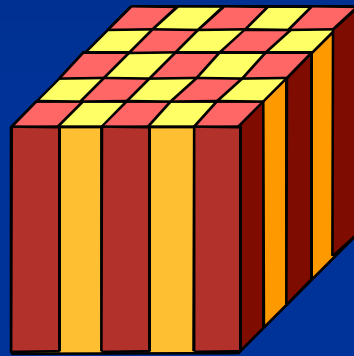
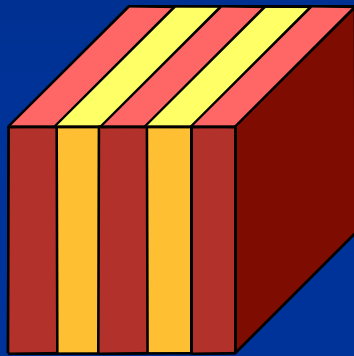


300  $\mu\text{m}$

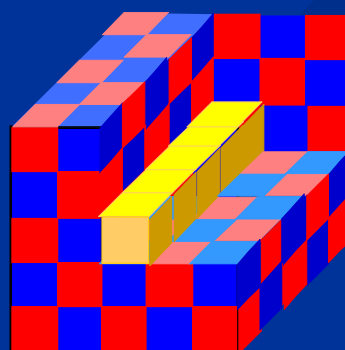
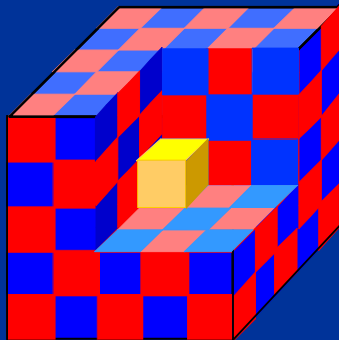
Photonic Crystal Slot  
Waveguide Spectrometer  
( $< 0.1$  lbs,  $< 10$ cu. cm.)

## ➤ What is Photonic Crystal?

- **Periodic** electromagnetic media comparable to wavelength
- With **photonic band gaps**: “optical insulators”



1-D grating = 1-D PhC  
2-D PhC = 2-D grating  
3-D PhC = 3-D grating  
Similar to:  
Semiconductors



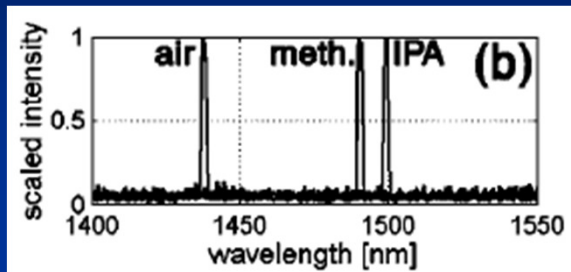
Defect structures can introduce  
defect mode inside the photonic  
bandgap  
Similar to: Doping of  
Semiconductor

can trap light in **cavities**

and **waveguides** (“wires”)

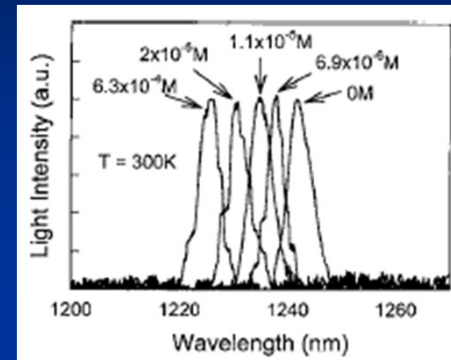
# Photonic Crystal Bio-Chemical Sensors

Sensing principle based on change in refractive index



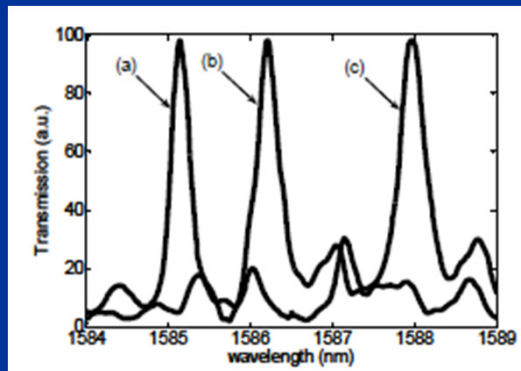
Chemical Sensing

Loncar et al, Appl. Phys. Lett. **82** (26), 4648 (2003)



Ion Sensing

Chakravarty et al, Optics Lett. **30** (19), 2578 (2005)



Bio-Sensing

Lee et al, Optics Exp. **15** (8), 4530 (2007)

Frontiers in Biological Detection: From Nanosensors to Systems, Conference 7888, SPIE Photonics West 2011

# Photonic Crystal Slot Waveguide Spectroscopy

Principle is based on Beer-Lambert absorption law:

$$I = I_0 \exp[-\gamma\alpha L]$$

where

- $I$  = Transmitted Intensity at the output of photonic crystal slot waveguide at wavelength  $\lambda$
- $I_0$  = Incident Optical power at wavelength  $\lambda$
- $L$  = Geometrical optical path length =  $300\mu\text{m}$
- $\gamma$  = Medium-specific absorption factor determined by dispersion enhanced light-matter interaction
- $\alpha$  = Absorption coefficient at wavelength  $\lambda$

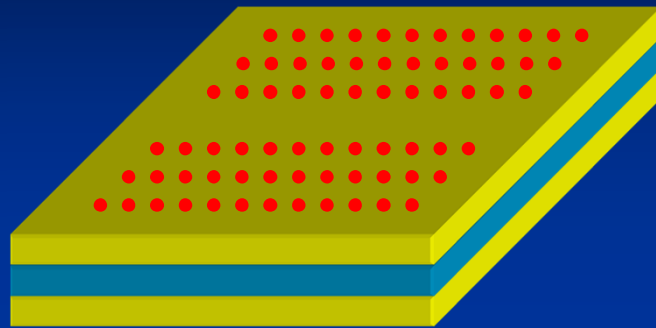
Mortensen et al, Appl. Phys. Lett. **90** (14), 141108 (2007)

$$\gamma = f \times \frac{c/n}{v_g}$$

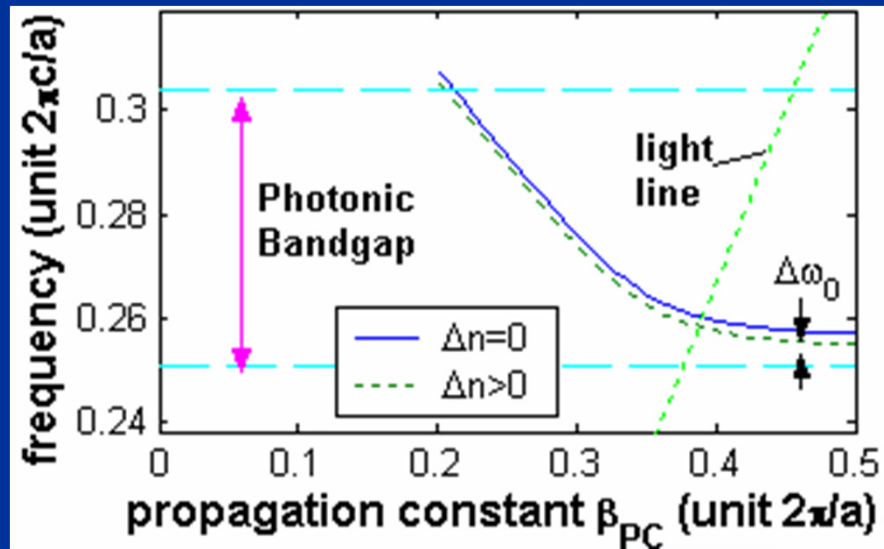
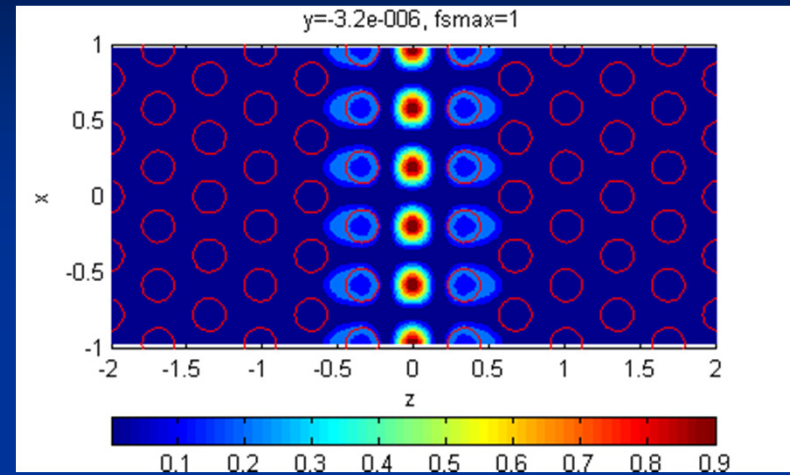
where

- $c$  = Velocity of light in medium of refractive index  $n$ .
- $v_g$  = Group velocity of light in the photonic crystal waveguide
- $f$  = Electric field intensity enhancement in the slot

## ➤ Photonic Crystal Waveguide

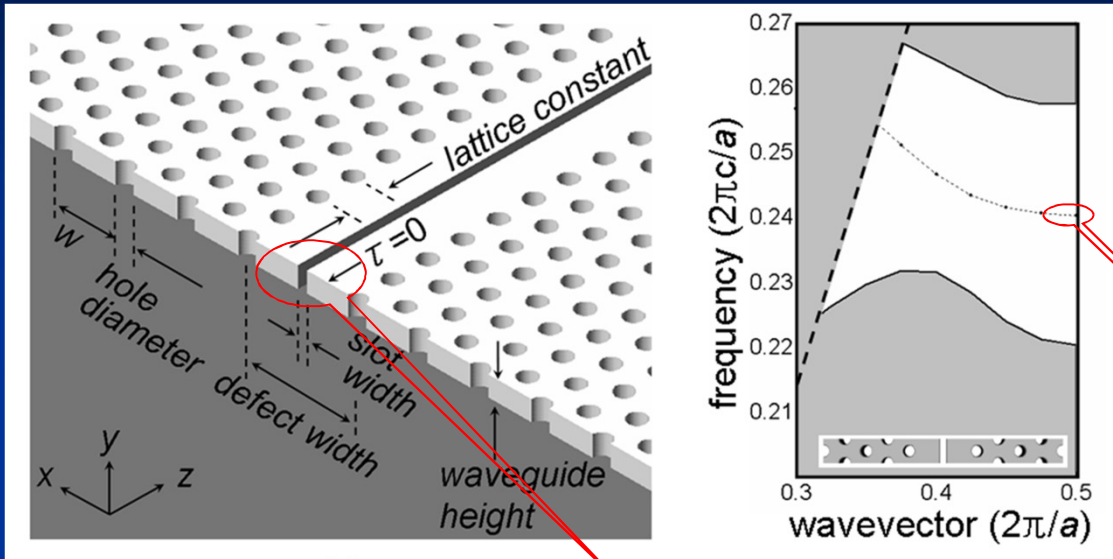


W-1 PCW



- Normalized dispersion diagram
- Scaled in wavelength by scaling the lattice constant of the photonic crystal

# ➤ Photonic Crystal Slot Waveguide



Photonic crystal period  $a=460\text{nm}$

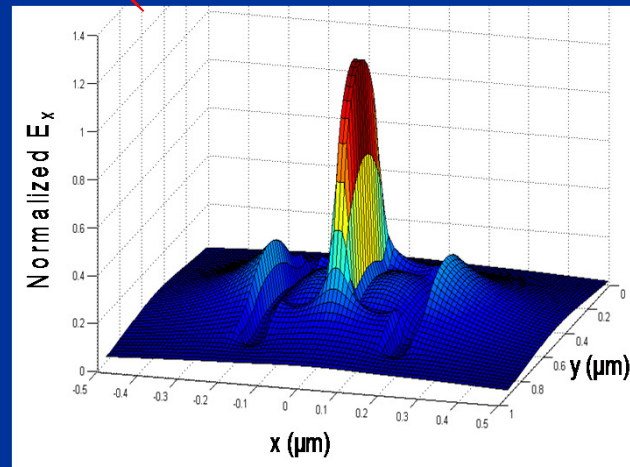
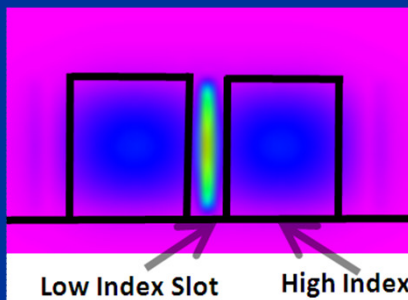
Waveguide height  $h=0.5a$

Hole diameter  $d=0.5a$

Slot width  $w_0=0.2a$

Defect width  $w_1=1.3\sqrt{a}$

## Slot Enhancement

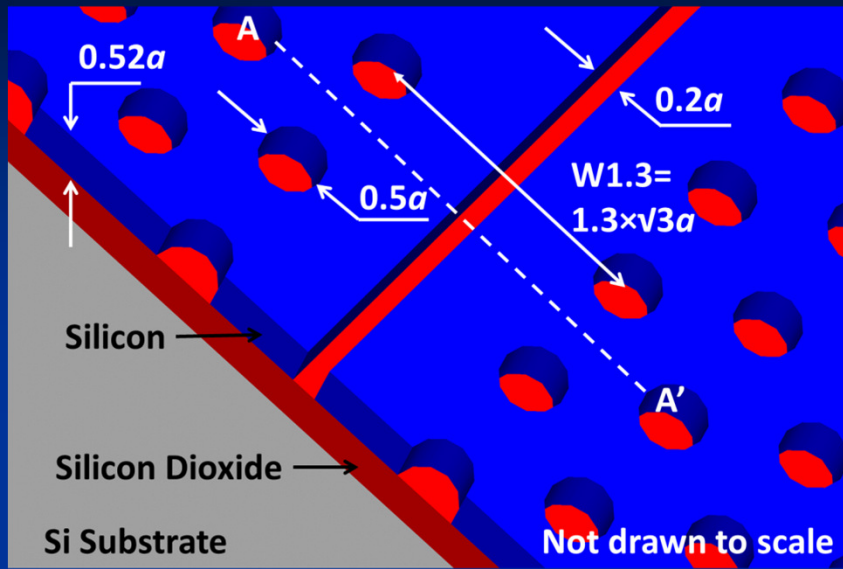


## Advantages:

- Slow photon group velocity
- Smaller mode profile
- Compatible fabrication processes with silicon photonics

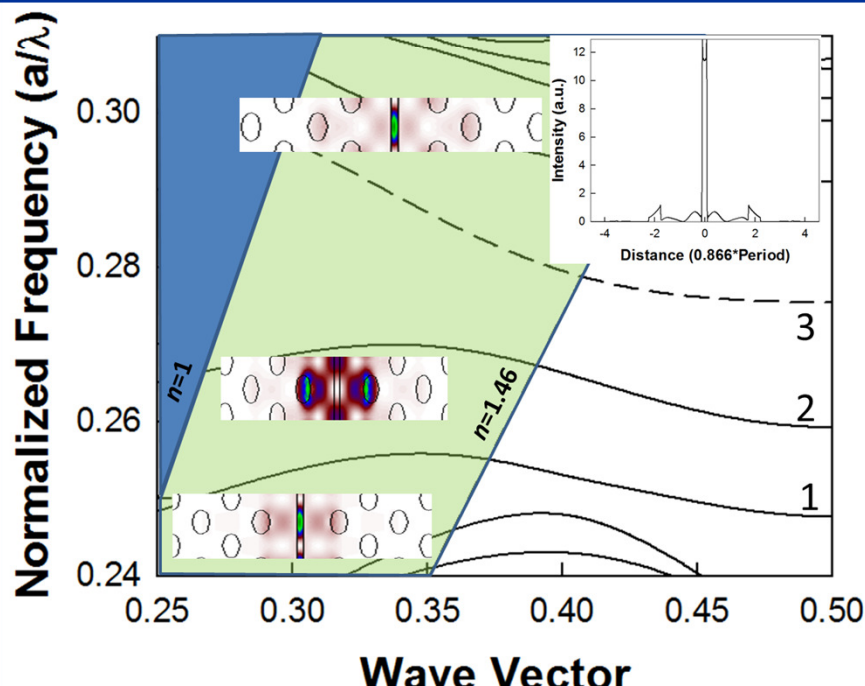
Xu et al, Optics Lett. 29  
1626 (2004)

# Photonic Crystal Slot Waveguide Design



## Device Parameters on a SOI wafer

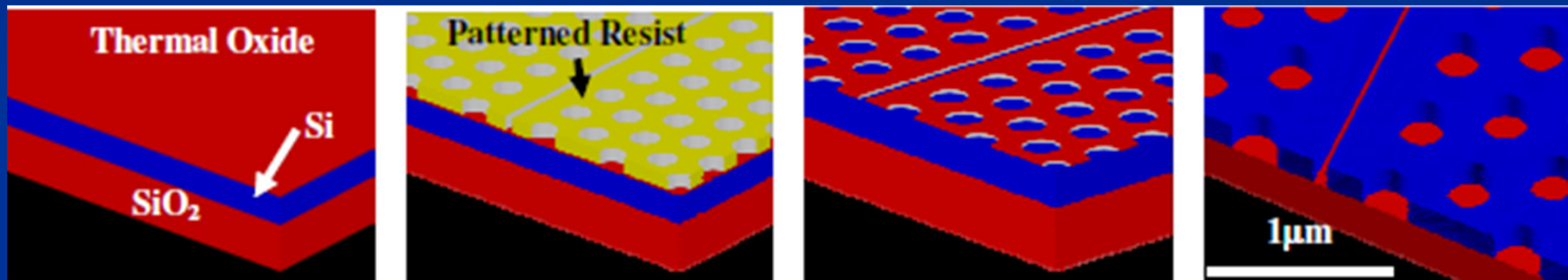
- Guided mode design in SOI wafer
- Factor of 12 enhancement in slot with mode 3.
- Designed for wavelength at which mode 3 has group index  $n_g=40$ , which coincides with the peak of the near-infrared absorption spectrum of methane at 1665.5nm.





# Device Fabrication Steps

## Standard silicon fabrication steps



**Thermal Oxide  
Growth**

**Resist Patterning**

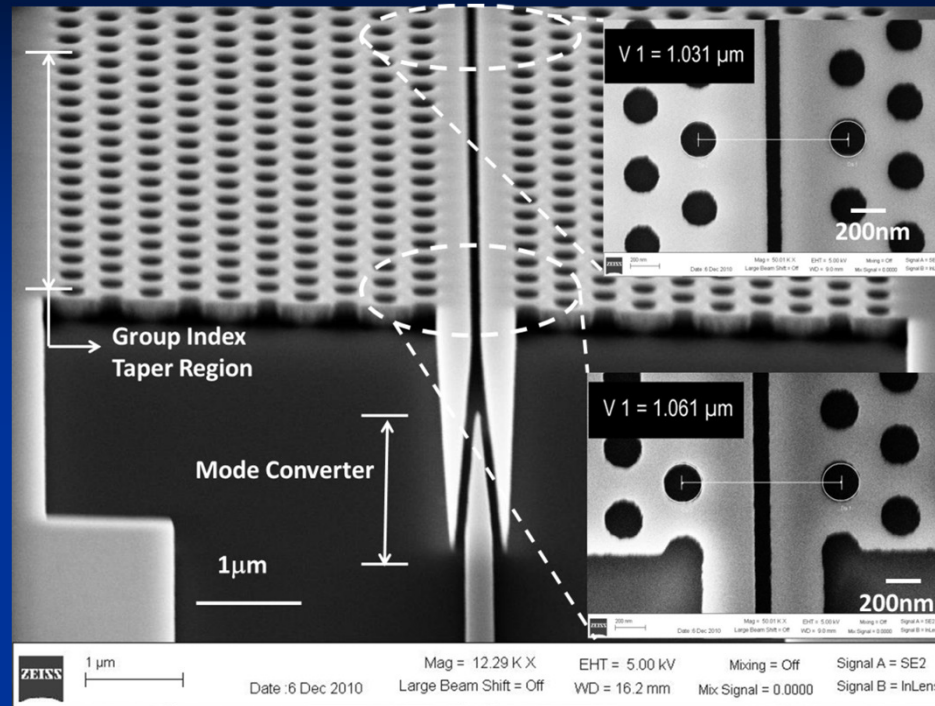
**Silicon Dioxide  
Hard Mask**

**Pattern transferred  
to Silicon**

**Structures considered with bottom SiO<sub>2</sub> cladding for mechanical stability for operation in harsh environments**

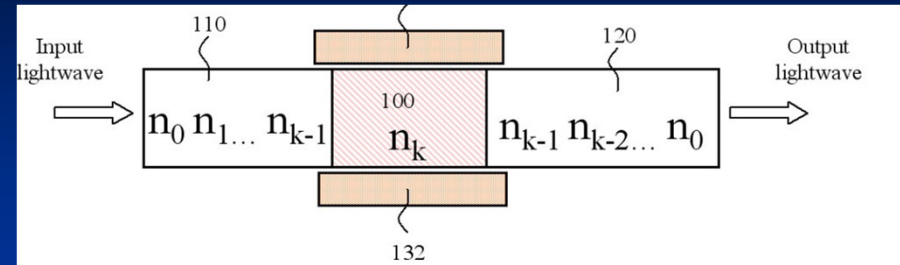
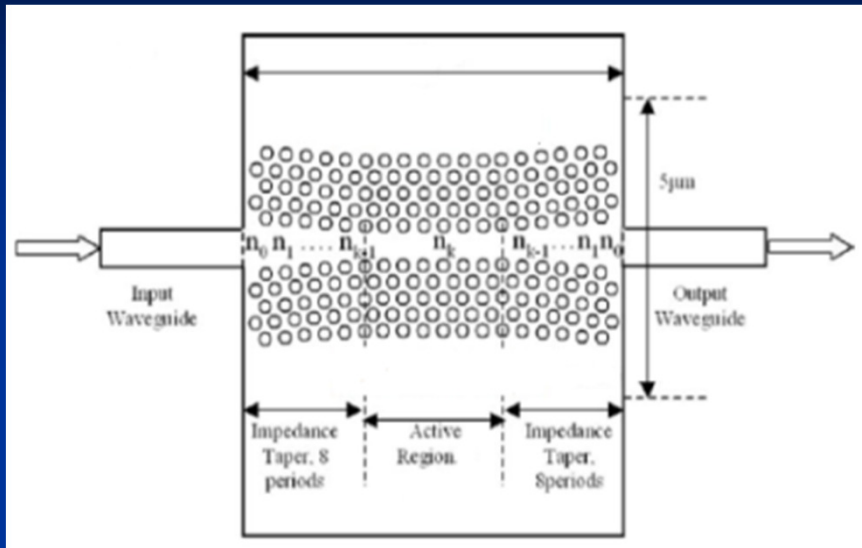
**Minimum feature sizes easily achievable by 193nm photolithography**

# Photonic Crystal Slot Waveguide



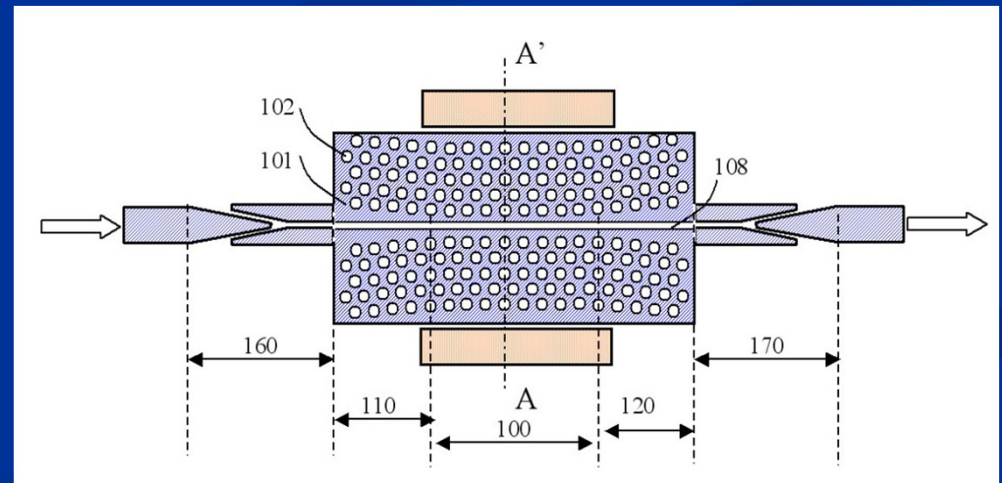
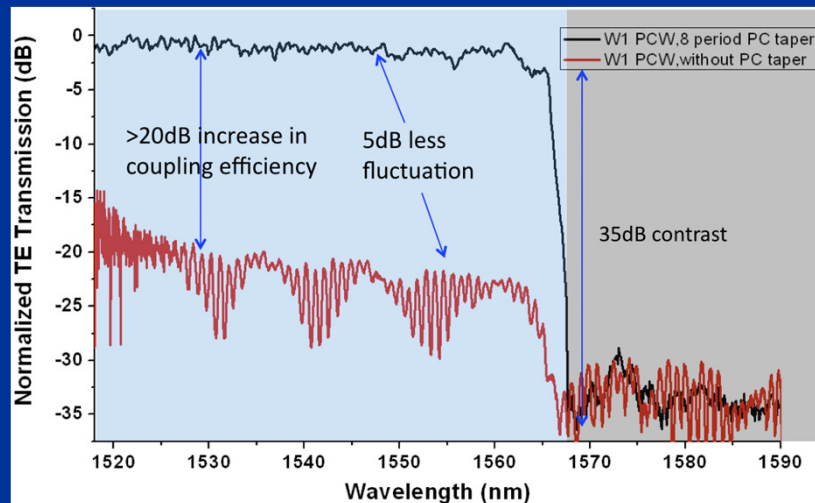
- Slot in the middle of a photonic crystal waveguide
- Mode Converter for higher coupling efficiency from the ridge waveguide into slot
- Photonic Crystal Impedance Taper for higher coupling efficiency into slow light region

# Methods to improve Optical Coupling Efficiency



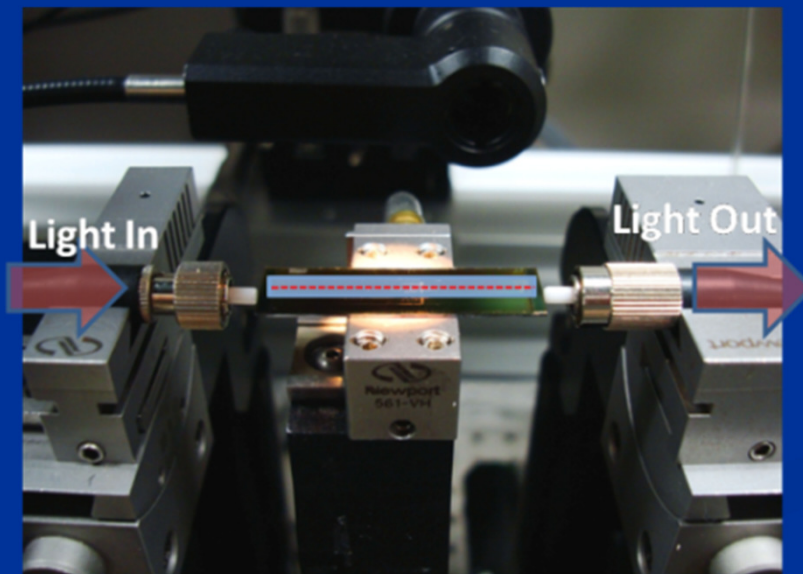
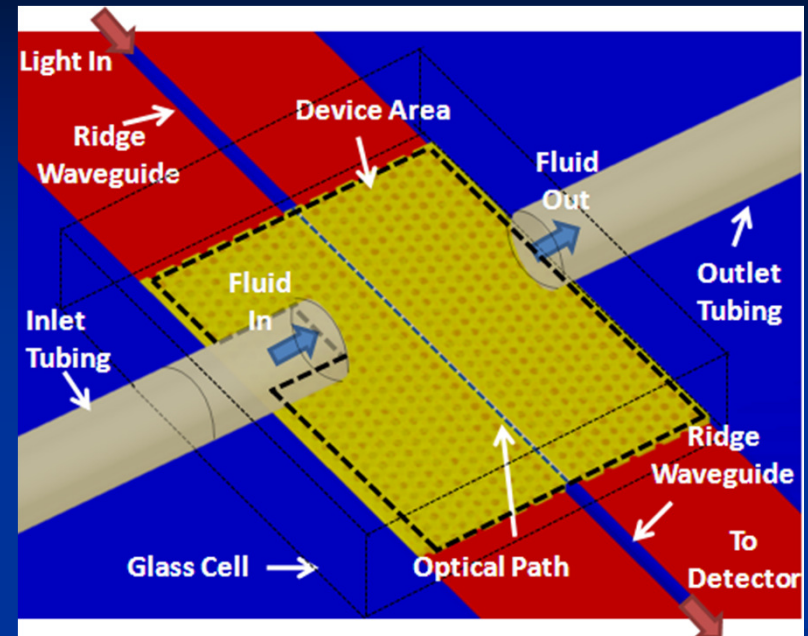
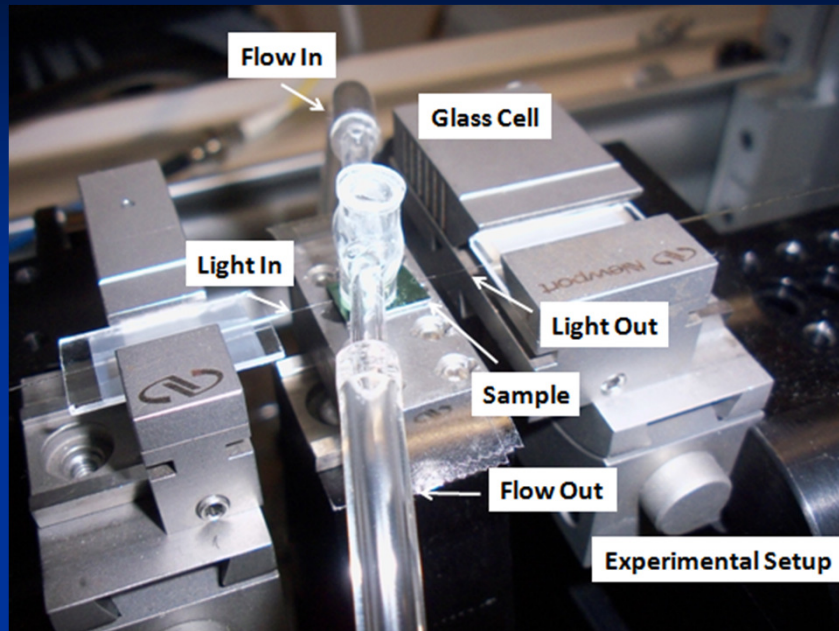
$$n_0=3.5 < n_1 < n_2 < \dots < n_{k-1} < n_k=100$$

- Group index varied gradually by shifting the edge air holes; from low group index at the ridge waveguide to high group index at the photonic crystal waveguide slow light regime.



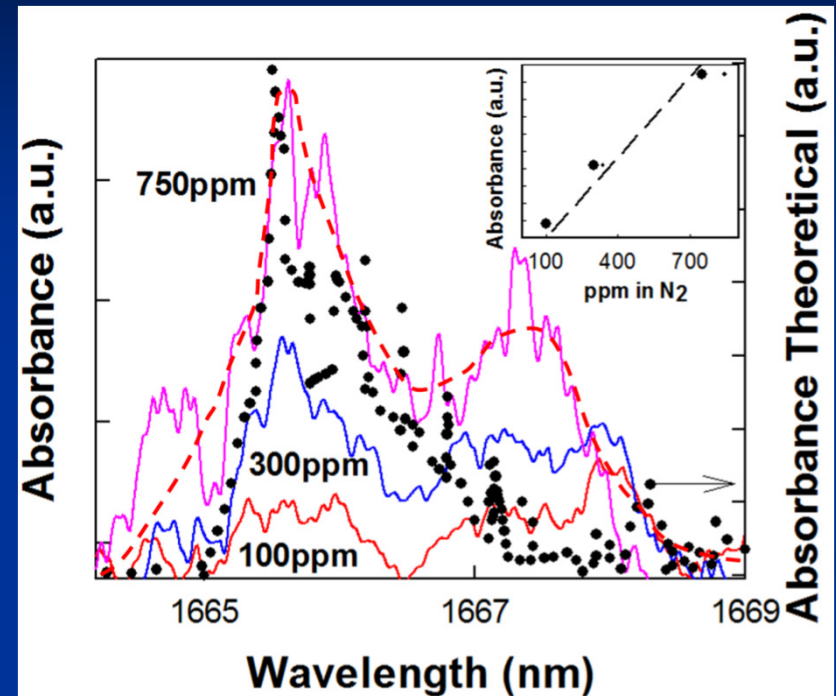
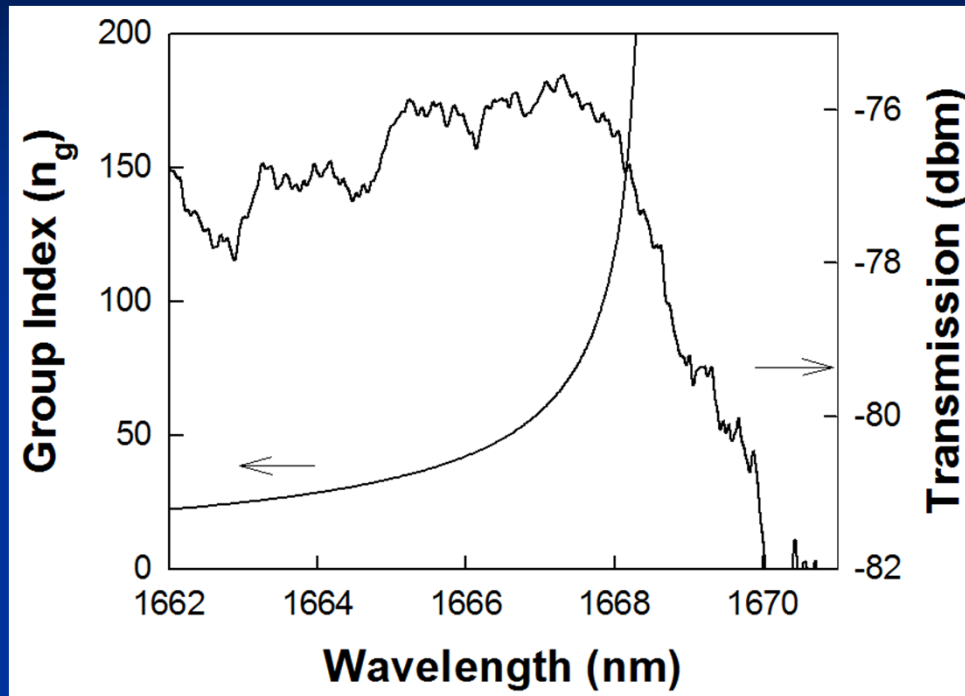
• Xiaolong Wang, Ray T. Chen, "Photonic Crystal Band-Shifting Device for Dynamic Control of Light Transmission," U.S. patent 455,791 (2009)

# Experimental Setup



- Light is guided in and out of the photonic crystal waveguide by optical fibers
- Light propagates in direction perpendicular to flow of fluid
- Sample cell for controlled environment during experiments; not required for final product

# Methane Detection in N<sub>2</sub> Ambient by Spectroscopy



- At 1.665 $\mu$ m, detection sensitivity of methane achieved for a 300 $\mu$ m long photonic crystal slot waveguide = 100ppm = 0.03ppm-m (=0.2% PEL)
- Experimentally,  $n_g \sim 30$ ; Slot enhancement  $\sim 12$
- More than an order of magnitude higher sensitivity can be achieved with wavelength/frequency modulation spectroscopy in near-IR (1ppm), on chip-integrated platform

# Requirements from Gas Sensors

Property	Requirement	Photonic Crystal Slot Waveguide Spectroscopy
Cost	< \$50/unit for single gas CH <sub>4</sub> sensor	High volume manufacturing in on-chip CMOS platform (< \$20)
Detection Sensitivity	<1% of LEL (500ppm for CH <sub>4</sub> )	Function of absorption cross-section (~40ppm Near-IR, ~400ppb Mid-IR)
Device Reusability / Longevity	5 years without recalibration or ~12 hours if battery-operated	No electronic components, longevity determined by silicon
Cross-Talk / False Positives/ Specificity	Minimum interference from other substances with signatures in similar wavelengths	Specificity achieved by multiple detection on-chip

- Sensitivity sufficient for most practical purposes
- More than an order of magnitude higher sensitivity can be achieved with wavelength/frequency modulation spectroscopy in near-IR (1ppm), on chip-integrated platform
- Absorbance cross-sections in mid-IR are 2 orders of magnitude larger (10ppb), on chip-integrated platform

# Comparison with other Technologies

Property	CRDS *	TDLAS **	FTIR †	PAS ‡	PC Slot Waveguide
On-Chip	No	No	No	No	Yes
Size	~1 cu. ft.	~0.5 cu. ft.	~1.4 cu. ft.	~1 cu. ft.	~0.015 cu. ft.
Weight	~28lbs	~6lbs	~24lbs	~33lbs	< 0.1lbs
Power	200 Watt	0.5 Watt	40 Watt	90 Watt	<0.1Watt
Portability	No	No	No	No	Yes
Sensitivity	0.002 ppm-m	1ppm-m (handheld)	0.05ppm-m	0.05ppm-m	0.012ppm-m (near-IR) # 0.12ppb-m(mid-IR)

\*CRDS: Cavity Ring-Down Spectroscopy; \*\*TDLAS: Tunable Diode Laser Absorption Spectroscopy; †FTIR: Fourier Transform Infrared Spectroscopy; ‡PAS: Photo-acoustic Spectroscopy; PC: Photonic Crystal

# Summary

**Photonic crystal Absorption spectrometers enable:**

- **Very low cost of ownership**
- **Sensitivity sufficient for most practical purposes**
- **Generous deployment of sensors in field**
- **Multiple species detection on-chip**
- **Less chance for false positives**

**Small size enables minimum interference with existing processes**

**In-situ detection and remote monitoring**

**Application Areas :**

- **Industrial process gas monitoring & quality control**
- **Air quality control & monitoring (Greenhouse and Hazardous Gases)**
- **Explosives detection**



# Discussion: Minimum Detectable Sensitivity

Smallest number density that can be determined by absorption spectroscopy

$$N_{\min} = \left(\frac{dI}{I_0}\right) / S(\nu)L$$

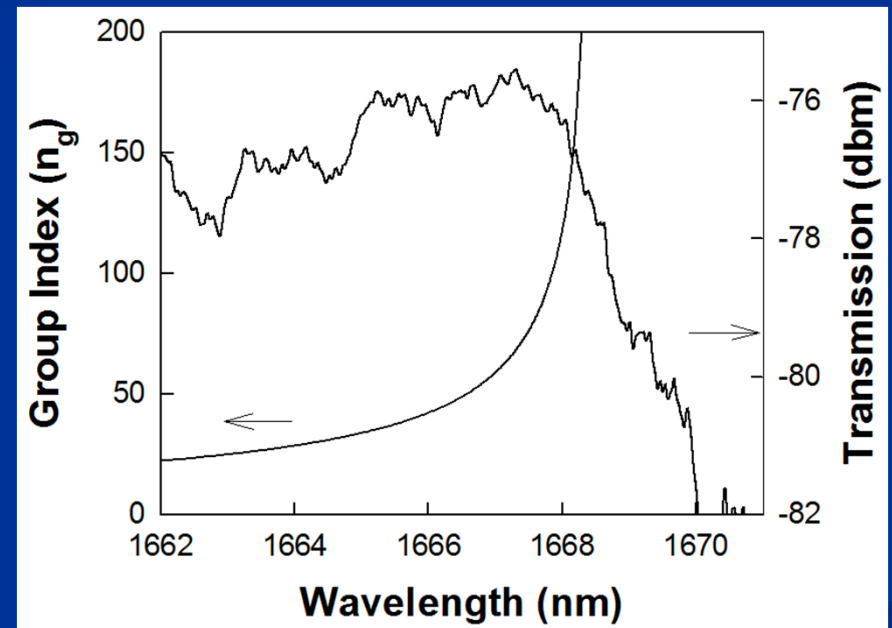
where

- $dI/I_0$  = smallest fractional change in light intensity that can be detected =  $5 \times 10^{-4}$
- $L$  = effective absorption path length =  $300\mu\text{m} \times 1000 = 30\text{cm}$
- $S(\nu)$  = absorption cross section of methane at  $1.665\mu\text{m} = 1.6 \times 10^{-20}\text{cm}^2$  [HITRAN]

$$N_{\min} = 1.04 \times 10^{15} \text{ per cm}^3$$

At  $1.665\mu\text{m}$ , detection limit of methane for a  $300\mu\text{m}$  long photonic crystal slot waveguide =  $40\text{ppm}$  (=0.15% LEL)

Experimentally,  $n_g \sim 30$ ; Slot enhancement  $\sim 12$



**Experimentally detected:  
100ppm = 0.03ppm-m**